NSN 5961-01-011-5398

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View Online at https://aerobasegroup.com/nsn/5961-01-011-5398
Inclosure Material:
Metal
Overall Length:
Between 0.480 inches and 0.535 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and mounting hardware
Overall Width Across Flats:
Between 0.855 inches and 0.875 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
325.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 18.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Test Data Document:
90536-7901448 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.,
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 wire hook and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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